Product data sheet

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NXP Semiconductors



Band-switching diode

BA277

FEATURES

- · Small plastic SMD package
- Continuous reverse voltage: max. 35 V
- Continuous forward current: max. 100 mA
- Low diode capacitance: max. 1.2 pF
- Low diode forward resistance: max. 0.7 Ω .

APPLICATIONS

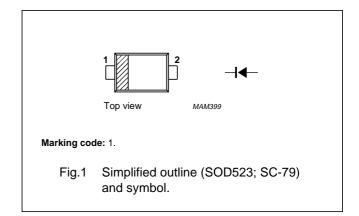
- · Low loss band switching in VHF television tuners.
- Surface mount band-switching circuits.

DESCRIPTION

Planar high performance band-switching diode in a small plastic SOD523 (SC-79) SMD package.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	35	V
I _F	continuous forward current		_	100	mA
P _{tot}	total power dissipation	T _s = 90 °C	_	715	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	I _F = 10 mA	1	V
I _R	reverse current	V _R = 25 V	50	nA
		V _R = 20 V; T _{amb} = 75 °C	1	μΑ
C _d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 6 \text{ V}$; note 1; see Fig.2	1.2	pF
r _D	diode forward resistance	I _F = 2 mA; f = 100 MHz; note 1; see Fig.3	0.7	Ω

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

THERMAL CHARACTERISTICS

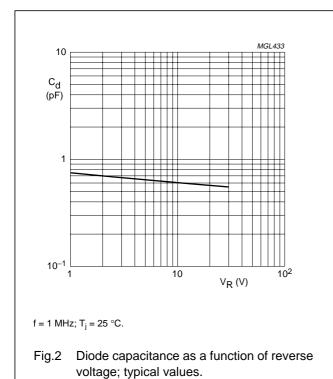
SYMBOL	PARAMETER		UNIT
R _{th j-s}	thermal resistance from junction to soldering-point		K/W

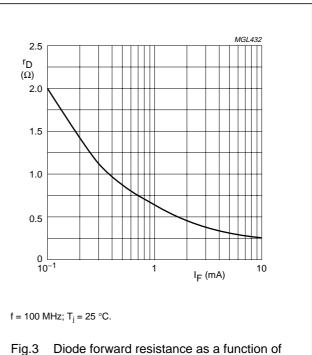
NXP Semiconductors Product specification

Band-switching diode

BA277

GRAPHICAL DATA





NXP Semiconductors Product specification

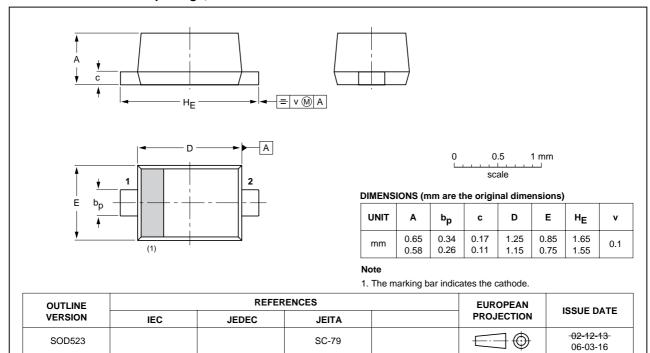
Band-switching diode

BA277

PACKAGE OUTLINE



SOD523



NXP Semiconductors BA277

Band-switching diode

Legal information

Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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NXP Semiconductors BA277

Band-switching diode

Revision history

Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BA277_N_2	20080107	Product data sheet	-	BA277_1
Modifications:	 Package ou 	tline on page 4 changed		
BA277_1 (9397 750 03793)	19980506	Product specification	-	-

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